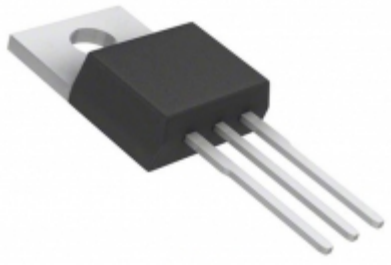


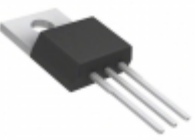
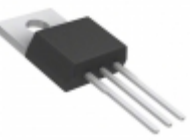



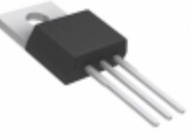
	<h2 style="color: red;">FQP32N12V2</h2>
	<p>Hersteller-Teilenummer: FQP32N12V2</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 120V 32A TO-220</p> <p>Datenblätter: 1.FQP32N12V2.pdf 2.FQP32N12V2.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 27600 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP32N12V2
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 120V 32A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	27600 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	150W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	120V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	32A (Tc)
Rds On (Max) @ Id, Vgs	50 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	53nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1860pF @ 25V
Verpackung	Tube



FQP32N12V2 ist neu im Original, Suche FQP32N12V2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP32N12V2 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP32N12V2: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP30N06 Fairchild/ON Semiconductor MOSFET N-CH 60V 30A TO-220</p>	 <p>FQP30N06L Fairchild/ON Semiconductor MOSFET N-CH 60V 32A TO-220</p>	 <p>FQP30N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A TO-220</p>	 <p>FQP32N20C Fairchild/ON Semiconductor MOSFET N-CH 200V 28A TO-220</p>
 <p>FQP32N20 FAIRCHI FQP32N20 FAIRCHI</p>	 <p>FQP30N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 30A TO-220</p>	 <p>FQP32N20C AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 28A TO-220</p>	 <p>FQP32N12V2 AMI Semiconductor / ON Semiconductor MOSFET N-CH 120V 32A TO-220</p>

heiße Teile

Mehr

 FQP20N06L	 FQP20N06L	 FQP20N06TSTU	 FQP20N06TSTU	 FQP20N60
 FQP22N30	 FQP22N30	 FQP22P10	 FQP22P10	 FQP24N08
 FQP24N08	 FQP24N40	 FQP27N25	 FQP27N25	 FQP27N60
 FQP27P06	 FQP27P06	 FQP2N60B	 FQP2N60C	 FQP2N60C
 FQP2N65C	 FQP30N06	 FQP30N06	 FQP30N06L	 FQP30N06L
 FQP32N12V2	 FQP32N20	 FQP32N20C	 FQP32N20C	 FQP33N10
 FQP33N10	 FQP33N10L	 FQP33N10L	 FQP34N20	 FQP34N20
 FQP34N20L	 FQP34N20L	 FQP3N50C	 FQP3N60C	 FQP3N60C
 FQP3N80C	 FQP3N80C	 FQP44N08	 FQP44N08	 FQP44N10
 FQP44N10	 FQP44N10F	 FQP44N10F	 FQP45N03L	 FQP45N03LM

Contact us: Info@Y-IC.com

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